

8500 nm Fabry-Perot Quantum Cascade Laser, 400 mW

QF8500HB



Description

The QF8500HB is a single spatial mode, multi longitudinal mode, Fabry-Perot quantum cascade laser contained in a high heat load (HHL) package, designed and manufactured by Thorlabs. This laser operates in continuous wave (CW) mode at room temperature.

The QF8500HB has a collimated output and offers a standard HHL pinout for electrical and temperature control. Its package is sealed, although the seal is not hermetic. There is no monitor photodiode.

Specifications

Absolute Maximum Ratings ($T_{CHIP} = 25^{\circ}C$, CW Operation)	
Absolute Max Operating Current	Varies Between Devices ^a
Absolute Max Output Power	0.7 W
LD Reverse Voltage (Max)	1 V
PD Reverse Voltage (Max)	N/A
TEC Current (Max)	8 A
TEC Voltage (Max)	14 V
Operating Temperature	25 to 40 $^{\circ}C^b$
Storage Temperature	-40 to 85 $^{\circ}C^b$



- The absolute maximum current is determined on a device-by-device basis and is listed on the device's data sheet.
- Non-condensing environment. Single spatial mode performance is guaranteed at 25 $^{\circ}C$.

Thermistor Characteristics ($T_{CASE} = 25^{\circ}C$)				
	Symbol	Min	Typical	Max
Thermistor Resistance ^a	R_{th}	-	10 k Ω	-
Steinhart-Hart Coefficients ($T_{case} = 25^{\circ}C$)	A	-	$1.129 \times 10^{-3} K^{-1}$	-
	B	-	$2.341 \times 10^{-4} K^{-1}$	-
	C	-	$0.878 \times 10^{-7} K^{-1}$	-

- Thermistor resistance follows the Steinhart-Hart equation:

$$\frac{1}{T} = A + B(\ln R_{th}) + C(\ln R_{th})^3$$

April 17, 2023

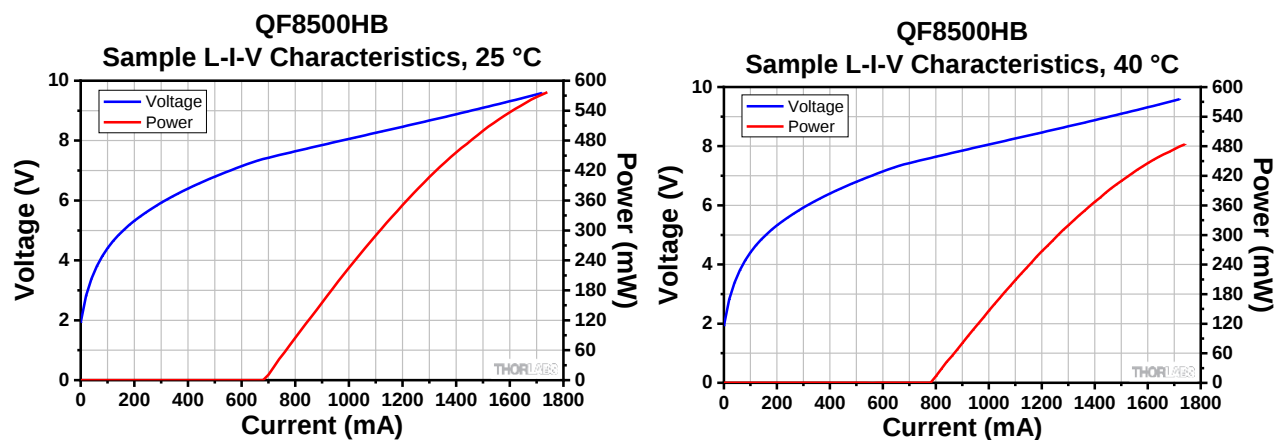
QTN051447-S01, Rev A

Specifications (Cont.)

Optical Electrical Characteristics ($T_{\text{CHIP}} = 25\text{ }^{\circ}\text{C}$, CW Operation)				
	Symbol	Min	Typical	Max
Center Wavelength	λ	8.2 μm	8.5 μm	8.8 μm
Spectral Bandwidth (5 - 95% Integrated Power)	$\Delta\lambda$	400 nm	500 nm	-
Optical Output Power	P_{out}	400 mW	500 mW	700 mW
Operating Current	I_{op}	-	1.5 A	2.0 A
Threshold Current	I_{th}	-	0.5 A	-
Forward Voltage	V_F	-	9 V	13 V
Beam Pointing	Parallel ^a	-	-0.75 $^{\circ}$	+0.75 $^{\circ}$
	Perpendicular ^a	-	-2.75 $^{\circ}$	-1.25 $^{\circ}$
Beam Divergence Angle (FWHM)	Parallel ^a	$\theta_{\parallel}$	3 mrad	6 mrad
	Perpendicular ^a	$\theta_{\perp}$	3 mrad	6 mrad
M^2	Parallel ^a	$M^2_{\parallel}$	1.0	1.3
	Perpendicular ^a	$M^2_{\perp}$	1.0	1.3
Minimum Beam Diameter (D4 σ Method) ^b	D	0.5 mm	1.5 mm	2.5 mm

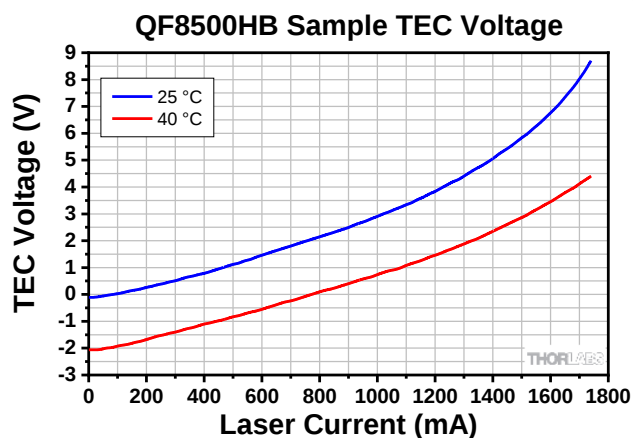
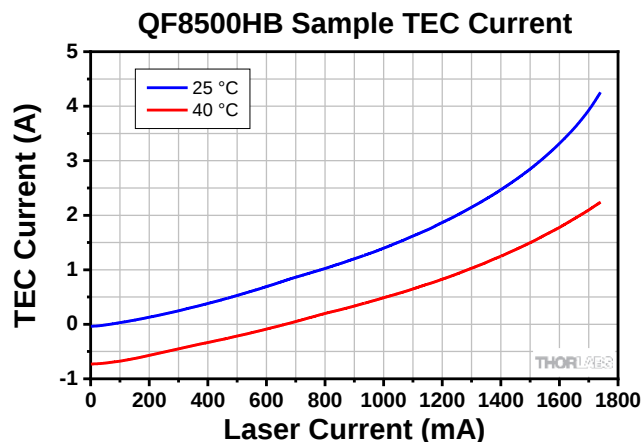
- a. For this laser, these terms are defined with respect to the plane of the base plate.
b. Obtained by scanning a razor across the beam and measuring the points where 10% of the total beam intensity and 90% of the total beam intensity are observed.

Sample Performance Plots

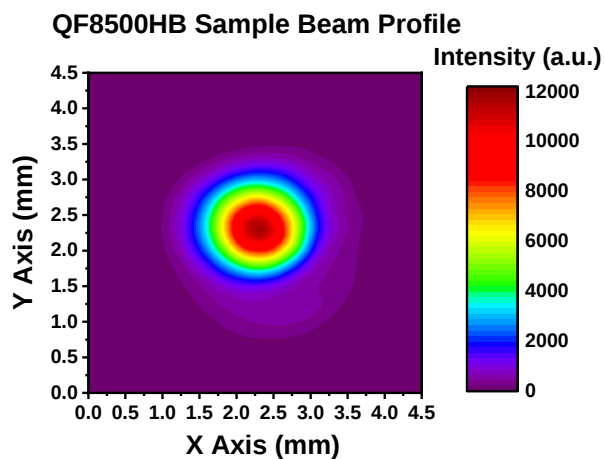
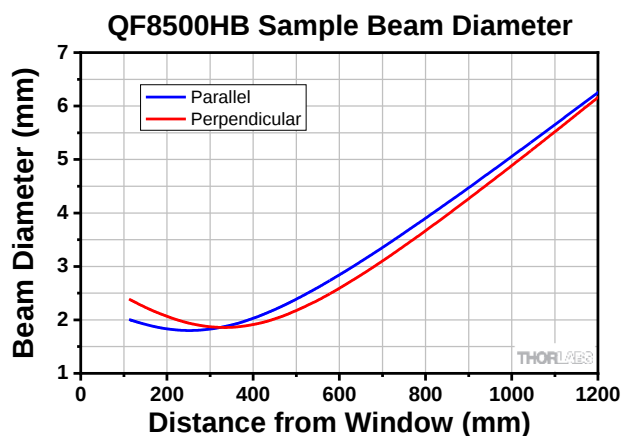
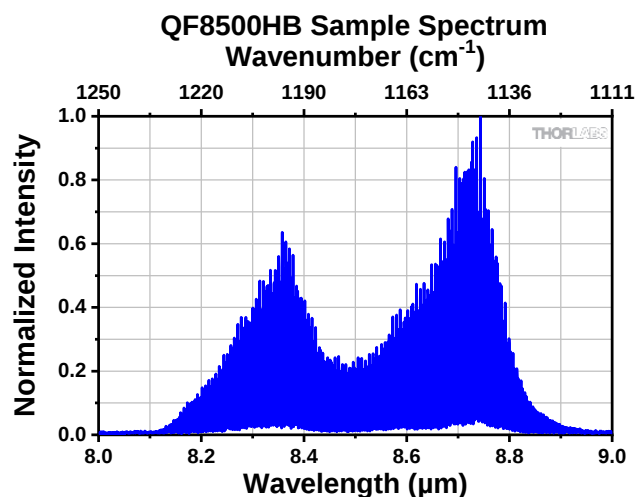


The temperatures given are for T_{CHIP} .

Sample Performance Plots (Cont.)

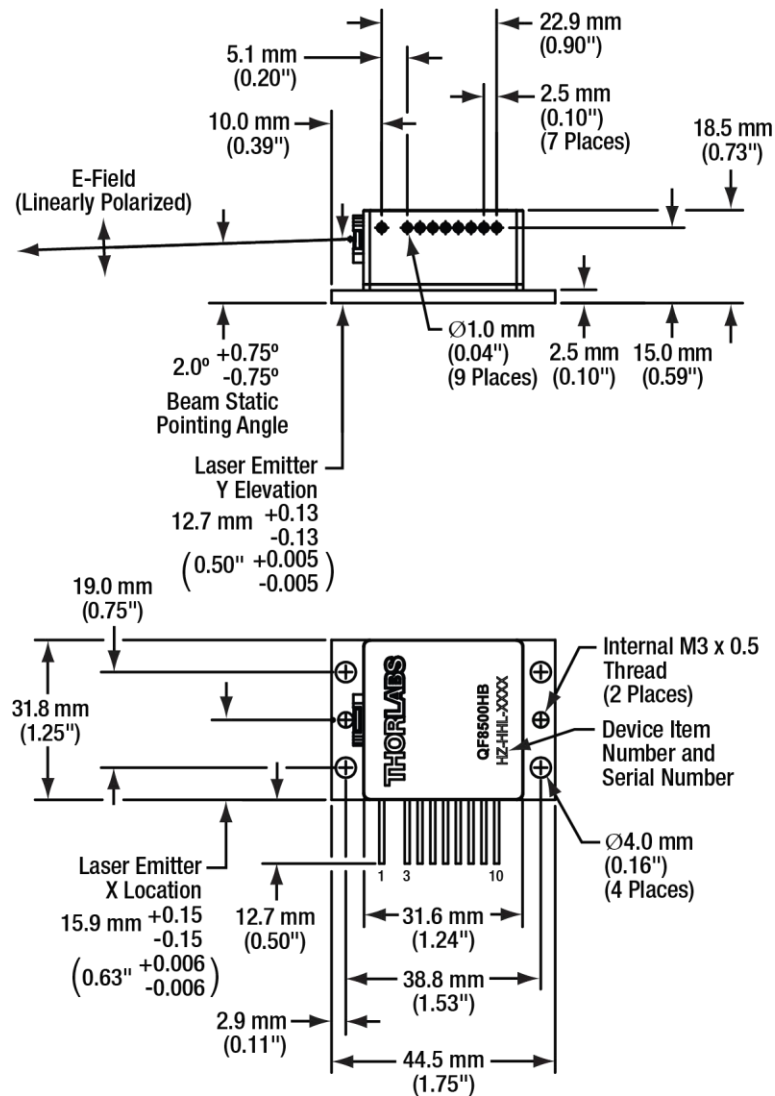


The data above is given at T_{CHIP} .



The beam profile was taken 310 mm from the sample.

Drawing for QF8500HB



Pin	Description
1	TEC (-)
2	Not Present
3	No Connection
4	Laser Anode (+)
5	TEC Control Thermistor, 10 k Ω
6	TEC Control Thermistor, 10 k Ω
7	Laser Cathode (-)
8	EEPROM (+)
9	EEPROM (-/Ground)
10	TEC (+)